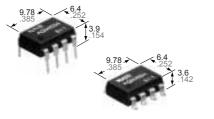


Panasonic

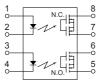
ideas for life

High sensitivity and low on-resistance. DIP (1 Form A/1 Form B) 8-pin type.

HE PhotoMOS (AQW654)



mm inch



FEATURES

- 1. Compact 8-pin DIP size
 The device comes in a compact (W)
 6.4×(L) 9.78×(H) 3.9 m (W) .252×(L)
 .385×(H) .154 inch, 8-pin DIP size
 (through hole terminal type).
- 2. Applicable for 1 Form A 1 Form B use as well as two independent 1 Form A and 1 Form B use
- **3. Controls low-level analog signals** PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- 4. High sensitivity, low ON resistance Can control a maximum 0.16 A (AQW654) load current with a 5 mA input current. Low ON resistance of 16 Ω (AQW654). Stable operation because there are no metallic contact parts.

- **5. Low-level off state leakage current** The SSR has an off state leakage current of several milliamperes, whereas the PhotoMOS relay has typ. 100 pA even with the rated load voltage of 400 V
- (AQW654). 6. Low thermal electromotive force (Approx. 1 μ V)

TYPICAL APPLICATIONS

- · High-speed inspection machines
- Data communication equipment
- Telephone equipment

TYPES

Туре	Output rating*			I	Packing quantity			
			Through hole terminal	Surface-mount terminal				
	Load voltage	Load current	Tube packing style		Tape and reel packing style			
					Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	Tube	Tape and reel
AC/DC	400 V	120 mA	AQW654	AQW654A	AQW654AX	AQW654AZ	1 tube contains 40 pcs. 1 batch contains 400 pcs.	1,000 pcs

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the SMD terminal shape indicator "A" and the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW654(A)	Remarks
	LED forward current	lF	50 mA	
Innut	LED reverse voltage	VR	5 V	
Input	Peak forward current	I FP	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW	
	Load voltage (peak AC)	VL	400 V	
Output	Continuous load current	IL	0.12A (0.16 A)	Peak AC, DC (): in case of using only 1 channel)
·	Peak load current	Ipeak	0.36 A	A connection: 100 ms (1 shot), V _L = DC
	Power dissipation	Pout	800 mW	
Total power dissipation		Рт	850 mW	
I/O isolation voltage		Viso	1,500 V AC	Between input and output/between contact sets
Tomporatura limita	Operating	Topr	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures
Temperature limits	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F	

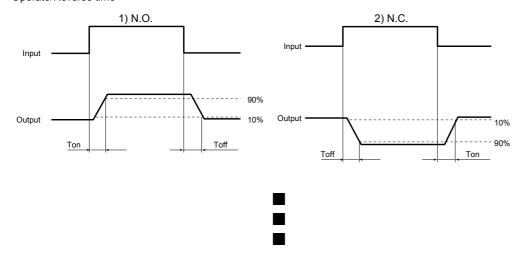
HE PhotoMOS (AQW654)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item				Symbol	AQW654(A)	Remarks	
Input	LED operate (OFF) current		Typical	IFon (N.O.)	0.9 mA	L = May	
	LED operate	(OFF) current	Maximum	IFoff (N.C.)	3 mA	⊢ I∟ = Max.	
	LED reverse	(ON) ourrent	Minimum	I _{Foff} (N.O.)	0.4 mA	I∟ = Max.	
	LED levelse	(ON) current	Typical	IFon (N.C.)	0.8 mA		
	LED dropout	Typical	V _F	1.25 V (1.14 V at I _F = 5 mA)	I _F = 50 mA		
	LED diopoui	voltage	Maximum	VF	1.5 V	TIF = 50 IIIA	
	On resistance		Typical	Ron	11 Ω		
Output	On resistant	e	Maximum	Kon	16 Ω		
Output	Off state lea	kage current	Maximum	Leak	1 μΑ	I _F = 0 mA (N.O.) I _F = 5 mA (N.C.) V _L = Max.	
	Switching speed	Operate (OFF) time*	Typical	Ton (N.O.)	0.8 ms (N.O.) 1.2 ms (N.C.)	I _F = 0 mA → 5 mA I _L = Max.	
			Maximum	Toff (N.C.)	2 ms		
Transfer characteristics		Reverse (ON) time*	Typical	Toff (N.O.)	0.04 ms (N.O.) 0.36 ms (N.C.)	I _F = 5 mA → 0 mA I _L = Max.	
			Maximum	Ton (N.C.)	1 ms		
	I/O capacitance		Typical	0	0.8 pF	f = 1 MHz	
	i/O capacitai	ice	Maximum	Ciso	1.5 pF	V _B = 0 V	
	Initial I/O iso	lation resistance	Minimum	Riso	1,000 MΩ	500 V DC	

Note: Recommendable LED forward current I_F = 5 mA.

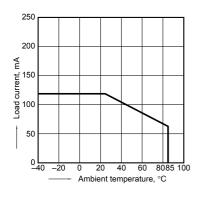
^{*}Operate/Reverse time



REFERENCE DATA

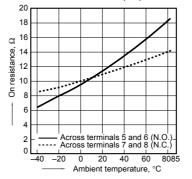
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



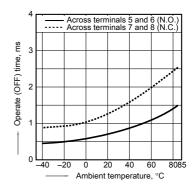
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



3. Operate (OFF) time vs. ambient temperature characteristics

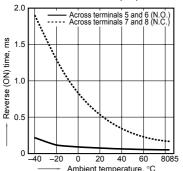
LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



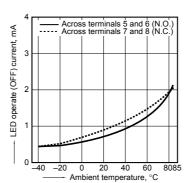
HE PhotoMOS (AQW654)

4. Reverse (ON) time vs. ambient temperature characteristics

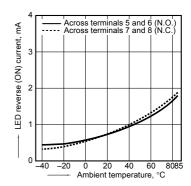
LED current: 5 mA; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



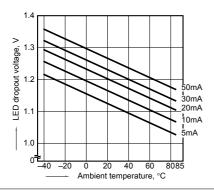
5. LED operate (OFF) current vs. ambient temperature characteristics Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)



6. LED reverse (ON) current vs. ambient temperature characteristics Load voltage: 400 V (DC); Continuous load current: 120 mA (DC)

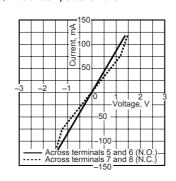


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



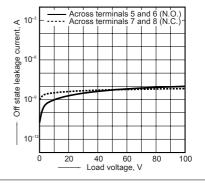
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



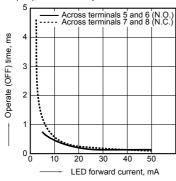
Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



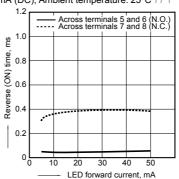
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77° F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz;

Ambient temperature: 25°C 77°F

